NSN 5961-00-890-9733

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-890-9733 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.092 inches and 0.130 inches **Mounting Method:** Terminal Features Provided: Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 22.0 breakdown voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** 82.0 pf capacitance **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0